SWITCHMODE™ Power Rectifier

The SWITCHMODE power rectifier employs the use of the Schottky Barrier principle with a Platinum barrier metal. This state-of-the-art device has the following features:

- Dual Diode Construction Terminals 1 and 3 May Be Connected for Parallel Operation at Full Rating
- 30 Volt Blocking Voltage
- Low Forward Voltage Drop
- Guardring for Stress Protection and High dv/dt Capability
- 150°C Operating Junction Temperature

Mechanical Characteristics

- Case: Epoxy, Molded. Epoxy Meets UL 94 V-0 @ 0.125"
- Weight: 4.3 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 Units Per Plastic Tube
- Marking: MBR7030WT
- ESD Ratings: Machine Model, B (< 400 V)

Human Body Model, 3B (> 8000 V)

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	V
Average Rectified Forward Current (Rated V_R , $T_C = 100$ °C) Per Leg Per Device		35 70	A
Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, T _C = 100°C)	I _{FRM}	70	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	500	A
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)	I _{RRM}	2.0	А
Storage Temperature Range	T _{stg}	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs

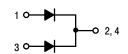
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

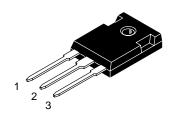


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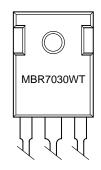
SCHOTTKY BARRIER RECTIFIER 70 AMPERES 30 VOLTS





TO-247AC CASE 340L STYLE 2

MARKING DIAGRAM



MBR7030WT = Device Code

ORDERING INFORMATION

Device	Package	Shipping
MBR7030WT	TO-247	30 Units/Rail

MBR7030WT

THE MADIC HARACTERISTICS (Per Diode)

Rating	Symbol	Max	Unit
Thermal Resistance – Junction to Case	$R_{ heta JC}$	0.55	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode)

Instantaneous Forward Voltage (Note 1.)	V _F		Volts
@ $I_F = 35 \text{ Amps}, T_C = 25^{\circ}\text{C}$		0.55	
@ $I_F = 70 \text{ Amps}, T_C = 25^{\circ}\text{C}$		0.72	
$@ I_F = 35 \text{ Amps}, T_C = 100^{\circ}\text{C}$		0.52	
Instantaneous Reverse Current (Note 1.)	I _R		mA
@ Rated DC Voltage, T _C = 25°C		5.0	
@ Rated DC Voltage, T _C = 100°C		250	

^{1.} Pulse Test: Pulse Width = $300 \mu s$, Duty Cycle < 2.0%

TYPICAL CHARACTERISTICS

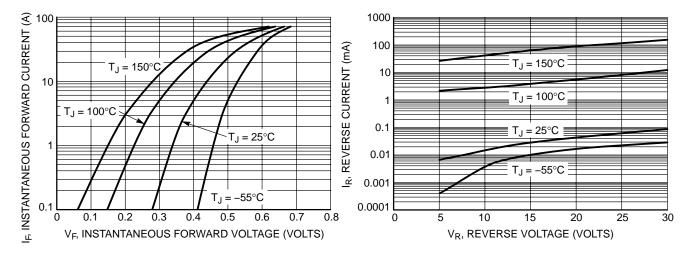


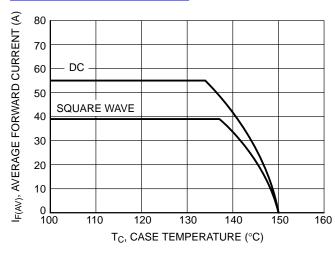
Figure 1. Typical Forward Voltage

Figure 2. Typical Reverse Current

MBR7030WT

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TYPICAL CHARACTERISTICS



 $P_{F(AV)}$, AVERAGE POWER DISSIPATION (WATTS) 45 40 35 SQUARE 30 WAVE 25 20 DC 15 10 5 30 40 50 60 I_{F(AV)}, AVERAGE FORWARD CURRENT (AMPS)

Figure 3. Current Derating (Case)

Figure 4. Forward Power Dissipation (Per Leg)

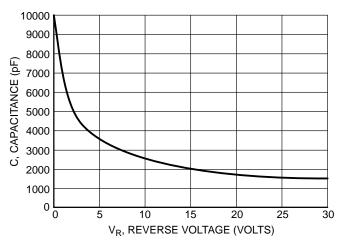


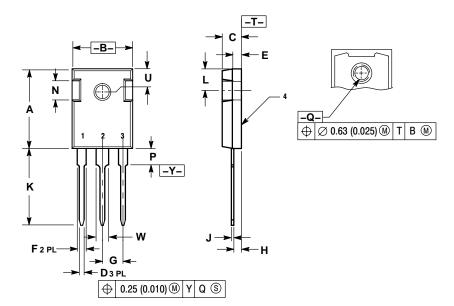
Figure 5. Typical Capacitance

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PACKAGE DIMENSIONS

TO-247 PSI PLASTIC CASE 340L-02 ISSUE D



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	20.32	21.08	0.800	8.30	
В	15.75	16.26	0.620	0.640	
С	4.70	5.30	0.185	0.209	
D	1.00	1.40	0.040	0.055	
E	2.20	2.60	0.087	0.102	
F	1.65	2.13	0.065	0.084	
G	5.45 BSC		0.215 BSC		
Н	1.50	2.49	0.059	0.098	
J	0.40	0.80	0.016	0.031	
K	20.06	20.83	0.790	0.820	
L	5.40	6.20	0.212	0.244	
N	4.32	5.49	0.170	0.216	
P		4.50		0.177	
Q	3.55	3.65	0.140	0.144	
U	6.15 BSC		0.242 BSC		
W	2.87	3.12	0.113	0.123	

STYLE 2:

- PIN 1. ANODE
 - 2. CATHODE (S)
 - 3. ANODE 2 4. CATHODES (S)

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